## NSN 5961-01-276-2450

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View Online at https://aerobasegroup.com/nsn/5961-01-276-2450 **Inclosure Material:** Ceramic **Overall Length:** 1.120 inches **Overall Height:** Between 0.160 inches and 0.190 inches Overall Width: Between 0.380 inches and 0.440 inches **End Application:** 4935-00-930-7250 test station, guided **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open and 80.0 collector to emitter voltage, dc with base short-circuited to emitter **Current Rating Per Characteristic:** 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 1000.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 18876-13218998 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:** 

**Fiig:** A110a0

**Demilitarization:** Yes - demil/mli